

/ Descriptions

TO-220 NPN Silicon NPN transistor in a TO-220 Plastic Package.

/ Features

2SA1129
Large current capacity with small package, low collector saturation voltage, pair with 2SA1129.

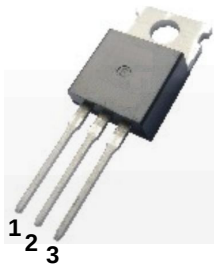
/ Applications

For low-frequency power amplifiers and mid-speed switching.

/ Equivalent Circuit



/ Pinning



PIN1 Base PIN 2 Collector PIN 3 Emitter

/ h_{FE} Classifications & Marking

h_{FE} Classifications Symbol	M	L	K	J
h_{FE} Range	40 80	60 120	100 200	160 320

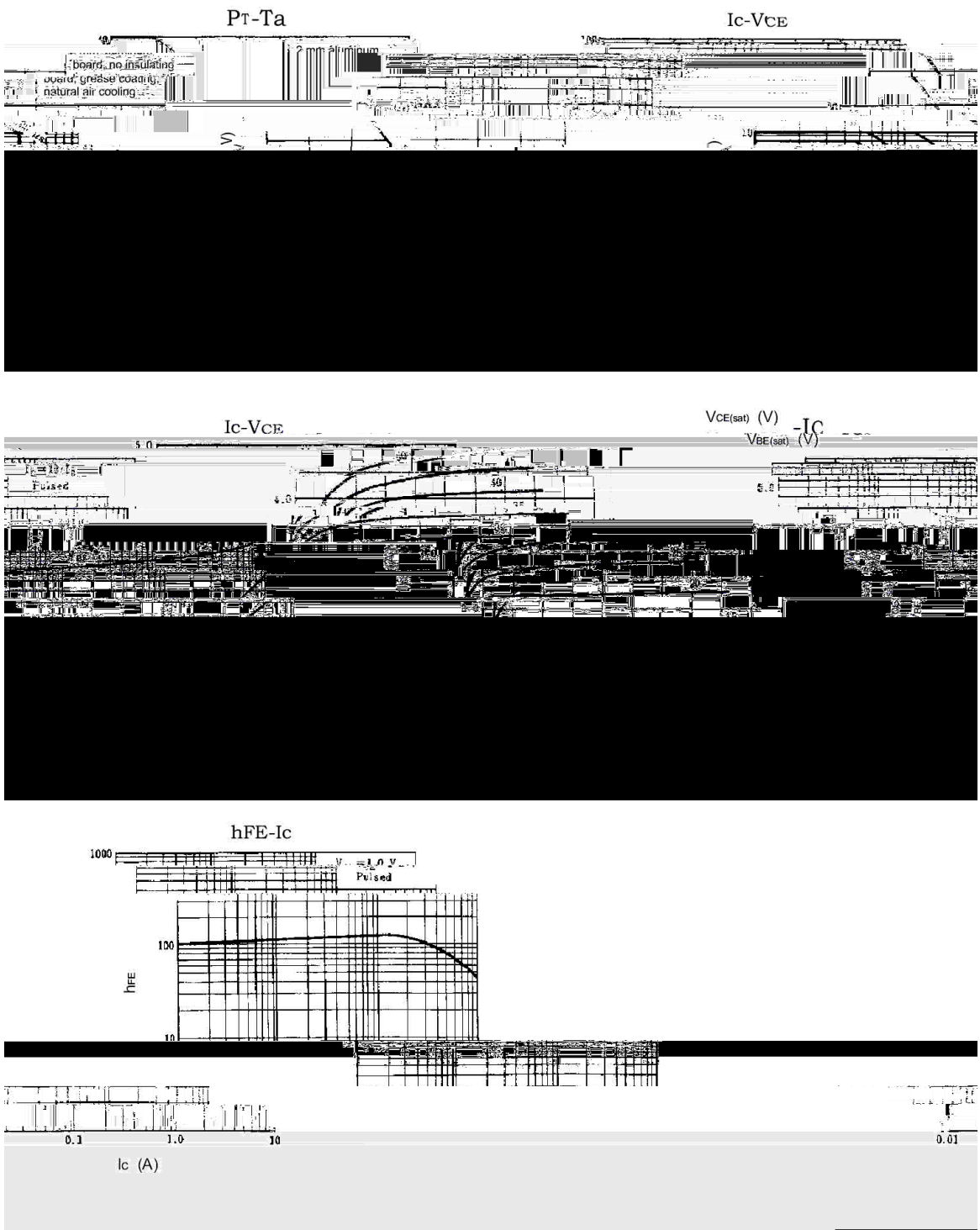
/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	100	V
Collector to Emitter Voltage	V_{CEO}	40	V
Emitter to Base Voltage	V_{EBO}	7.0	V
Collector Current - Continuous	I_C	7.0	A
Collector Current – Continuous(Pulse)	I_{CP}	15	A
Base Current - Continuous	I_B	3.5	A
Collector Power Dissipation	$P_C(T_C=25)$	40	W
	P_C	1.5	W
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

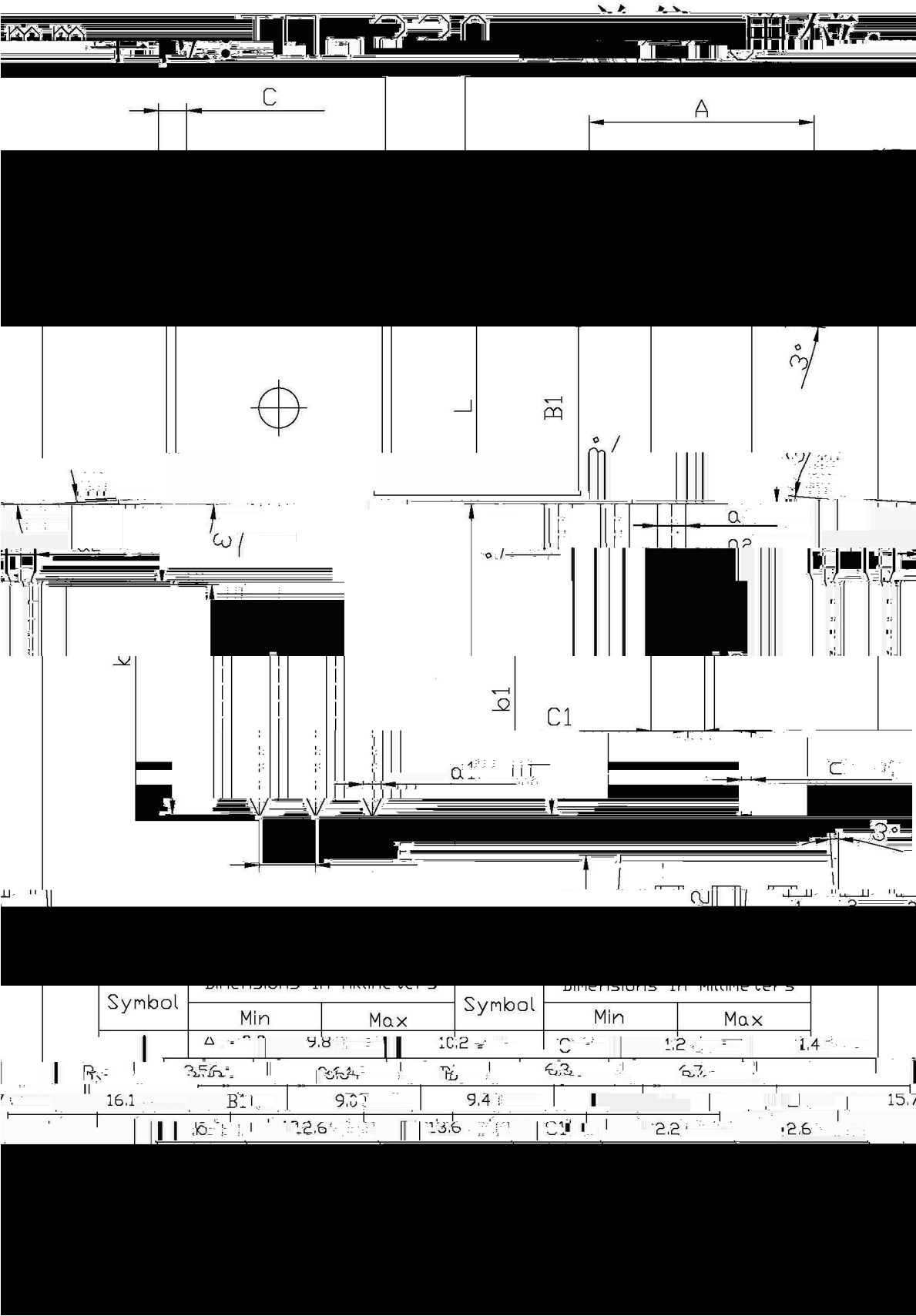
/ Electrical Characteristics(Ta=25)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=40V$ $I_E=0$			10	A
Emitter Cut-Off Current	I_{EBO}	$V_{EB}=5.0V$ $I_C=0$			10	A
DC Current Gain	$h_{FE(1)}$	$V_{CE}=1.0V$ $I_C=3.0A$	40		320	
	$h_{FE(2)}$	$V_{CE}=1.0V$ $I_C=5.0A$	20			
Collector to Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C=3.0A$ $I_B=0.1A$			0.3	V
	$V_{CE(sat)(2)}$	$I_C=5.0A$ $I_B=0.5A$			0.6	V
Base to Emitter Saturation Voltage	$V_{BE(sat)(1)}$	$I_C=3.0A$ $I_B=0.1A$			1.5	V
	$V_{BE(sat)(2)}$	$I_C=5.0A$ $I_B=0.5A$			2.0	V
Turn-On Time	t_{on}	$I_C=5.0A$ $R_L=4.0$			1.0	s
Storage Time	t_{stg}	$I_{B1}=-I_{B2}=0.5A$, $V_{CC} 20V$ $PW 50 s$			2.5	s
Fall Time	t_f	duty cycle 2%			1.0	s

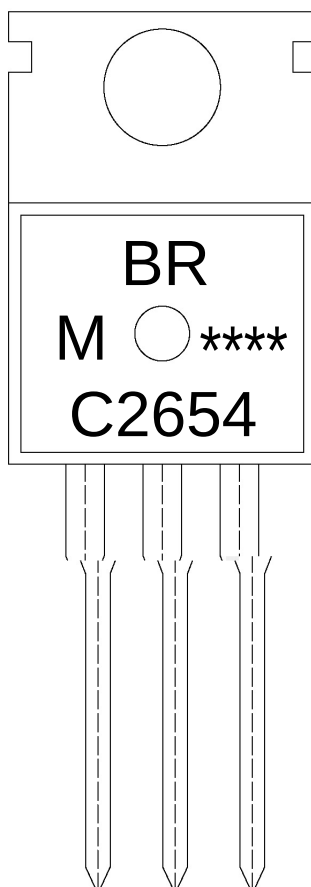
/ Electrical Characteristic Curve



/ Package Dimensions



/ Marking Instructions



BR

C2654

M:

h_{FE}

Note:

BR:

Company Code

C2654:

Product Type.

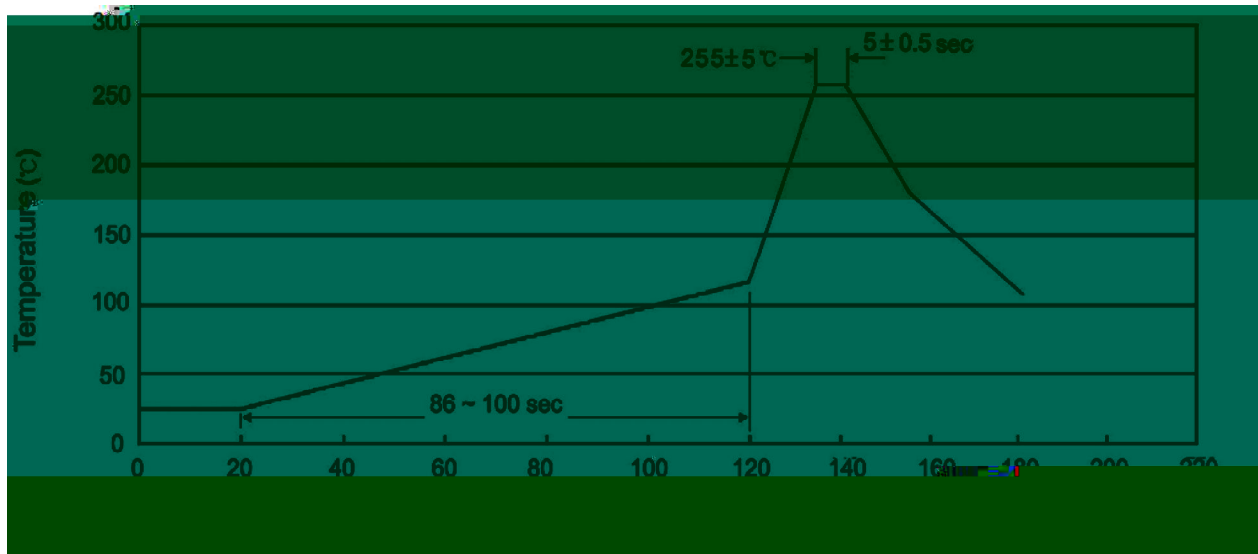
M:

h_{FE} Classifications Symbol

****:

Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



Note:

- | | | | |
|---|----------|-------------|---|
| 1 | 25 ~ 150 | 60 ~ 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | 5±0.5sec; | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 | 2 ~ 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Bag 只/袋	Bags/Inner Box 袋/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Bag 袋	Inner Box 盒	Outer Box 箱
TO-220/F	200	10	2,000	5	10,000	135×190	237×172×102	560×245×195

/ TUBE

Package Type 封装形式	Units 包装数量				Dimension 包装尺寸 (unit: mm ³)		
	Units/Tube 只/套管	Tubes/Inner Box 套管/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box			